ECE 107 Project

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Part 1

Formulas are given for completeness of the project report

Integral equation method



- Given
 - Two conductors
 - Voltage on the conductors is $V_0/2$ and $-V_0/2$ Find the capacitance CV=- $V_0/2$ surface C

$$V = -V_0/2$$
 surface $S^{(2)}$

Formulation

- Potential on the surfaces is given by $V_0/2$ and $-V_0/2$ Potential everywhere is calculated as $V(\mathbf{r}) = \int_{s}^{s} \frac{1}{4\pi\epsilon_0 |\mathbf{r} \mathbf{r}'|} \underbrace{\rho_s(\mathbf{r}')}_{\text{surface charge}} dS'$ where ρ_s is an unknown surface charge
- Equate the potentials on the surfaces

$$\implies \iint_{S^{(1)}+S^{(2)}} \frac{1}{\underbrace{4\pi\varepsilon_{0} \mid \mathbf{r} - \mathbf{r'} \mid}_{\text{Green's function}}} \underbrace{\rho_{s}(\mathbf{r'})}_{\text{surface charge distribution (unknown)}} dS' = \begin{cases} V_{0}/2; \mathbf{r} \in S_{1} \\ -V_{0}/2; \mathbf{r} \in S_{2} \end{cases} \leftarrow \text{integral equation}$$

Numerical capacitance extraction (3)

- Matrix equation and solution
 - Matrix equation $\underline{\underline{ZQ}} = \underline{V}$ $\left[Z_{mm} \approx \frac{1}{2\varepsilon_0 \sqrt{\pi \Delta s_n}}; \text{ self-patch} \right]$ $\underline{Z}: N \times N \text{ matrix}; Z_{mn} = \frac{1}{\Delta s_n} \iint_{S_n} \frac{ds'}{4\pi\varepsilon_0 |\mathbf{r}_m - \mathbf{r}'|} \Rightarrow \begin{cases} Z_{mn} \approx \frac{1}{2\varepsilon_0 \Delta s_n} \left(-d + \sqrt{\frac{\Delta s_n}{\pi} + d^2} \right); x_m = x_n \& y_m = y_n \end{cases}$ $\underline{Q}: N \text{ vector}; Q_n = \rho_s(\mathbf{r}_n) \Delta s_n$ $\underline{V}: N \text{ vector}; V_m = \begin{cases} V_0/2; \mathbf{r}_m \in S_1 \\ -V_0/2; \mathbf{r}_m \in S_2 \end{cases}$ For the case of parallel plates

- Solution
$$Q = Z^{-1}V$$

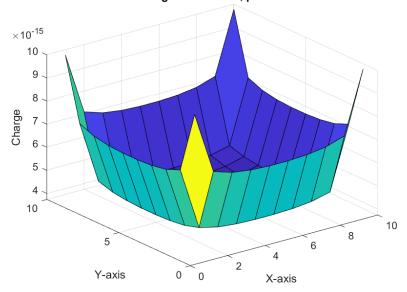
Extracted capacitance $C = \frac{\sum_{\substack{\text{charge on surface 1} \\ V_0}}^{\text{total}} \Rightarrow C = \frac{\sum_{n=1}^{N_{S_1}} Q_n}{V_0}$

```
function [C,Q1,Q2] = part2(Npatch_in_width,w,d)
   % Variable initilization
    epsilon0 = 8.85e-12;
   % w = 1e-2; % value from part3
   % d = 3e-3; % value from part3
   Ns1 = Npatch_in_width * Npatch_in_width; % Patch for S1
   Ns2 = Npatch_in_width * Npatch_in_width; % Pathch for S2
   N = Ns1 + Ns2; % Total Patch
   dw = w/Npatch_in_width; % width of single patch
   V0 = 1; % Initial Voltage
   % Construct the rm and rn
   d_bottom = 0;
   d \text{ top} = d \text{ bottom} + d;
   rm\_top = zeros(Npatch\_in\_width*Npatch\_in\_width,3); % (x = 1,y = 2,z = 3) for top plates
   rn_bottom = rm_top; % for bottom plates
    rm_top(:,3) = d_top;
    rn_bottom(:,3) = d_bottom;
    loop_index = 1;
    for x = 1:Npatch_in_width
       for y = 1:Npatch_in_width
                rn_bottom(loop_index,1) = dw*x;
                rm_top(loop_index,1) = dw*x;
                rn_bottom(loop_index,2) = dw*y;
                rm_{top(loop_index,2)} = dw*y;
                loop_index = loop_index +1;
       end
   end
   rm = [rm_top;rn_bottom];
```

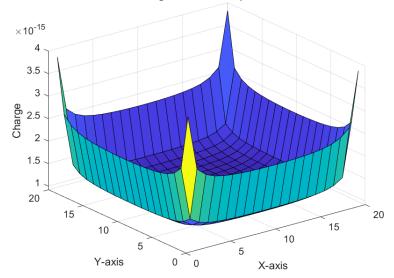
```
% Calculate Z vector
    Z = zeros(N,N);
    deltaSn = dw*dw;
    for m = 1:N
       for n = 1:N
            if m ~= n
                Z(m,n) = 1/(4*pi*epsilon0*norm(rm(m,1:3) - rm(n,1:3)));
            elseif ((rm(m,1) == rm(n,1)) && (rm(m,2) == rm(n,2)))
                Z(m,n) = 1/(2*epsilon0*deltaSn)*(-1*d+sqrt(deltaSn/pi + d*d));
                Z(m,n) = 1/(2*epsilon0*sqrt(pi*deltaSn));
            end
        end
    % Q vector
    Q = zeros(N,1);
    % V vector
    V = zeros(N,1);
    V(1:N/2) = V0/2; % Top plate
    V(N/2+1:N) = -V0/2; % Bottom Plate
    % Solution:
    Q = Z \setminus V;
    Q1 = Q(1:N/2); % Top charge
    Q2 = Q(N/2+1:N); % botoom charge
    Q1_sum = sum(Q1(1:N/2));
    C = Q1_sum/V0;
end
```

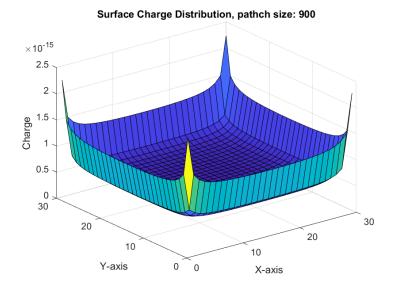
Before the new addition

Surface Charge Distribution, pathch size: 100

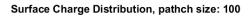


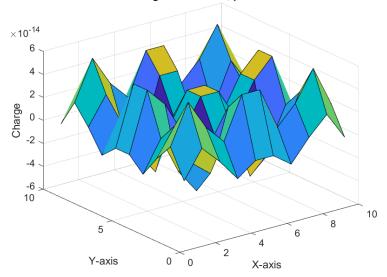
Surface Charge Distribution, pathch size: 400

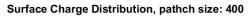


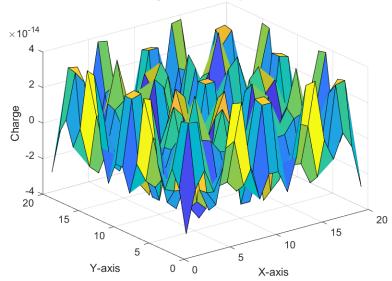


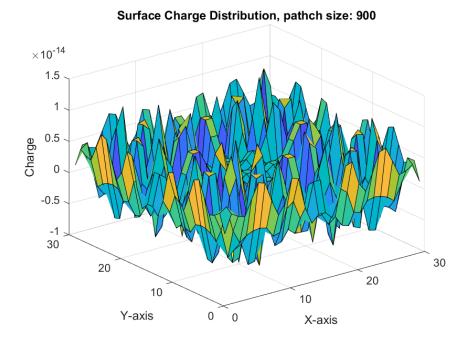
After the new condition:



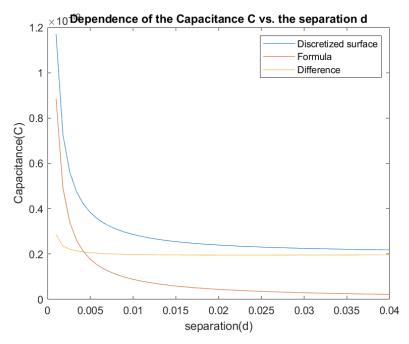




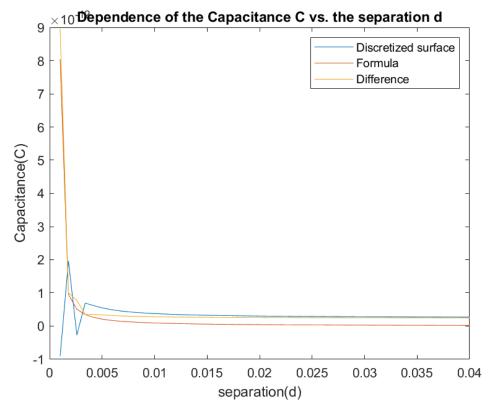




Before the new condition



after the new condition



```
function part4(Npatch)
    w = 1e-2; % value from part4
    d = 4e-2; % value from part4
   loop_index = 1;
    epsilon0 = 8.85e-12;
    totalpoints = 50;
    for x = linspace(0.1e-3,d,totalpoints)
        [C, Q1, Q2] = part2(Npatch, w, x);
        C_discret_array(loop_index) = C;
        C_formula_array(loop_index) = epsilon0 * w^2/x;
        C_difference(loop_index) = abs(C-C_formula_array(loop_index));
        loop_index = loop_index + 1;
    separation = linspace(1e-3,d,totalpoints);
    plot(separation,C_discret_array);
    hold on
    plot(separation, C_formula_array);
    plot(separation, C_difference);
    xlabel('separation(d)');
    ylabel('Capacitance(C)');
    title('Dependence of the Capacitance C vs. the separation d');
    legend('Discretized surface', 'Formula', 'Difference');
    saveas(gcf, 'Dependence of the Capacitance C vs the separation d.png');
```

50 points are taken for the above plot.

The result of the formula is closer to the results of the numerical solution when the separation distance is really small. Once the separation gets bigger, the difference of the results is distinguishable